



NPN MEDIUM POWER TRANSISTORS IN SOT223

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEO} > 45V & 80V
- I_C = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Complementary PNP Type: BCP5316Q
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The BCP5416Q and BCP5616Q are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Applications

- Medium Power Switching or Amplification Applications
- · AF Drivers and Output Stages

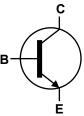
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

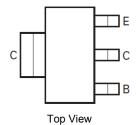
SOT223



Top View



Device Symbol



Pin-Out

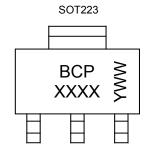
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCP5616QTA	Automotive	BCP 5616	7	12	1,000
BCP5616QTC	Automotive	BCP 5616	13	12	4,000
BCP5416QTA	Automotive	BCP 5416	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BCP = Product Type Marking Code, Line 1 XXXX = Product Type Marking Code, Line 2 as follows:

BCP5416 = 5416 BCP5616 = 5616

YWW = Date Code Marking \overline{Y} or Y = Last Digit of Year (ex: 0= 2020) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCP5416	BCP5616	Unit	
Collector-Base Voltage	V _{CBO}	45 100		V	
Collector-Emitter Voltage	V _{CEO}	45	80	V	
Emitter-Base Voltage	V _{EBO}	5		V	
Continuous Collector Current	I _C	1		А	
Peak Pulse Collector Current	I _{CM}	2			
Continuous Base Current	I _B	100		mA	
Peak Pulse Base Current	Івм	200			

Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)		P _D	2	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	62	°C /W
Thermal Resistance, Junction to Leads (Note 6)		$R_{ heta JL}$	19.4	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

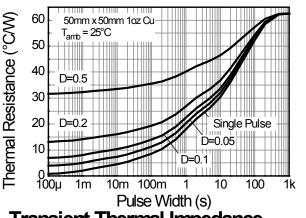
^{5.} For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

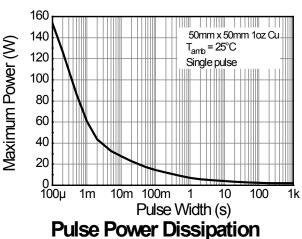
6. Thermal resistance from junction to solder-point (at the end of the collector lead).

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Transient Thermal Impedance

Max Power Dissipation (W) 2.0 50mm x 50mm 1oz Cu 1.5 1.0 0.5 0.0 40 60 80 100 120 Temperature (°C) 140 160

Derating Curve



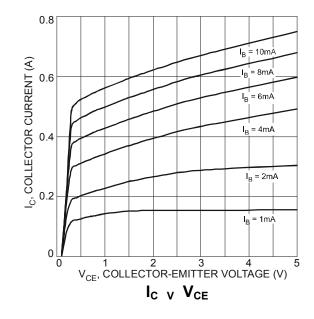
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

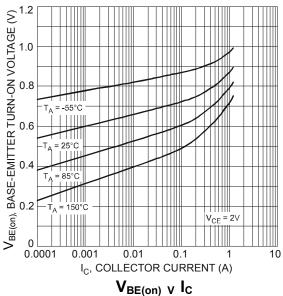
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
Collector-Base BCP5416		BV _{CBO}	45			V	Ic = 100µA	
Breakdown Voltage	BCP5616	D A CBO	100	_		V	IC = 100μA	
Collector-Emitter	BCP5416	DV	45		_	\ /	I _C = 10mA	
Breakdown Voltage (Note 8)	BCP5616	BV _{CEO}	80			V		
Emitter-Base Breakdown Voltage		BV _{EBO}	5	_	_	V	I _E = 100μA	
Collector Cut-Off Current					0.1	μA	V _{CB} = 30V	
Collector Cut-Off Current		I _{CBO}	_	_	20	μA	$V_{CB} = 30V, T_A = +150^{\circ}C$	
Emitter Cut-Off Current		I _{EBO}	-	_	20	nA	V _{EB} = 4V	
DC Current Gain (Note 8)		h _{FE}	25		_		$I_C = 5mA$, $V_{CE} = 2V$	
			100	_	250	_	$I_C = 150 \text{mA}, V_{CE} = 2 \text{V}$	
			25		_		$I_C = 500 \text{mA}, V_{CE} = 2V$	
Collector-Emitter Saturation Voltage (Note 8)		V _{CE(sat)}	-	_	0.5	V	I _C = 500mA, I _B = 50mA	
Base-Emitter Turn-On Voltage (Note 8)		V _{BE(on)}	_	_	1.0	V	I _C = 500mA, V _{CE} = 2V	
Transition frequency		f _T	100	150	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz	
Output Capacitance	C _{obo}	_	_	25	pF	V _{CB} = 10V, f = 1MHz		

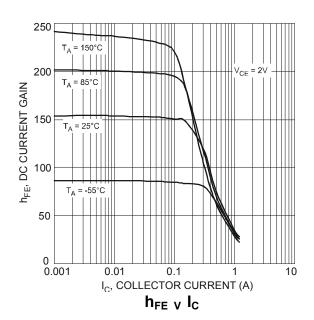
Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

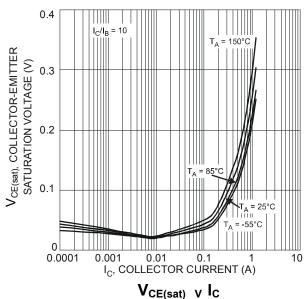


Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)



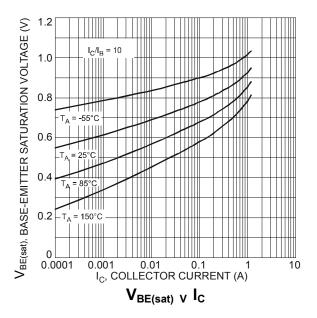


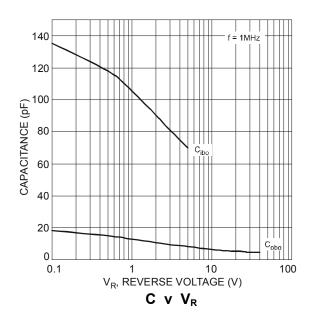


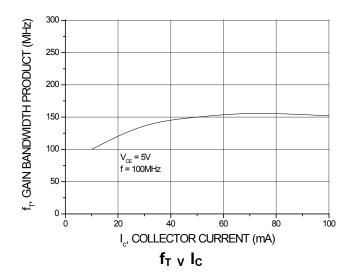




Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)



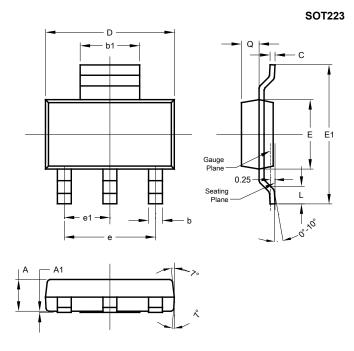






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

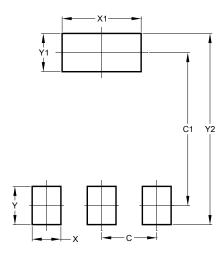


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
V2	0.00



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